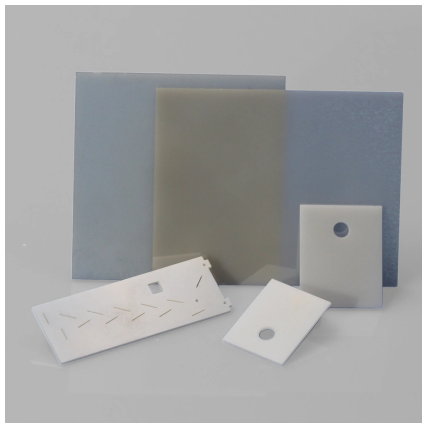




Machined AlN ceramic substrates with holes, slots and cut-outs

Laser Precision-Machined Aluminum Nitride Substrates

Product ID / SKU: FWM/CS-ALN-006

Material: Aluminum Nitride

Product type: Ceramic Substrate

AlN substrates with drawing-defined laser outlines, holes and precision features for electronic assembly.

95% AlN Substrate Properties

Property	95% AlN typical value	Condition / method
AlN content (%)	95	-
Density (g/cm ³)	≥3.3	-
Flexural strength (MPa)	≥400	-
Thermal conductivity (W/(m·K))	≥170	Room temperature
Relative permittivity	8-10	1 MHz; room temperature
Dielectric loss tangent	≤0.0003	1 MHz; room temperature
Dielectric strength (kV/mm)	17	-
Volume resistivity (Ω·cm)	≥10 ¹⁴	-